

AP2121

General Description

The AP2121 series are positive voltage regulator ICs fabricated by CMOS process. Each of these ICs consists of a voltage reference, an error amplifier, a resistor network for setting output voltage, a current limit circuit for current protection and a chip-enable circuit (5-pin products only).

The AP2121 series feature high supply voltage ripple rejection, low dropout voltage, low noise, high output voltage accuracy, and low current consumption which make them ideal for use in various battery-powered devices.

The AP2121 series have 1.2V, 1.3V, 1.5V, 1.8V, 2.5V, 2.8V, 2.8V, 3.0V, 3.2V and 3.3V versions.

The AP2121 are available in standard SOT-23-3, SOT-23-5 and CSP-4 packages.

Features

- Low Dropout Voltage at I_{OUT}=100mA: 150mV
 Typical (Except 1.2V, 1.3V and 1.5V Versions)
- Low Standby Current: 0.1μA Typical
- Low Quiescent Current: 25µA Typical
- High Ripple Rejection: 70dB Typical (f=1kHz)
- Output Current: More Than 200mA (300mA Limit)
- Extremely Low Noise: 30μVrms (10Hz to 100kHz)
- Excellent Line Regulation: 4mV Typical
- Excellent Load Regulation: 12mV Typical
- High Output Voltage Accuracy: ±2%
- Excellent Line Transient Response and Load Transient Response
- Compatible with Low ESR Ceramic Capacitor (as Low as $1\mu F$)

Applications

- Mobile Phones, Cordless Phones
- Wireless Communication Equipment
- Portable Games
- · Cameras, Video Recorders
- Sub-board Power Supplies for Telecom Equipment
- Battery Powered Equipment

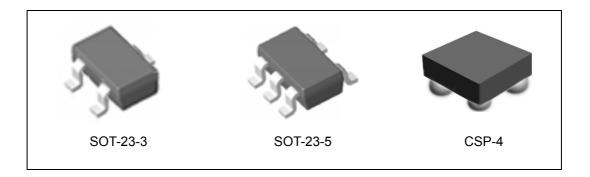


Figure 1. Package Types of AP2121



Pin Configuration

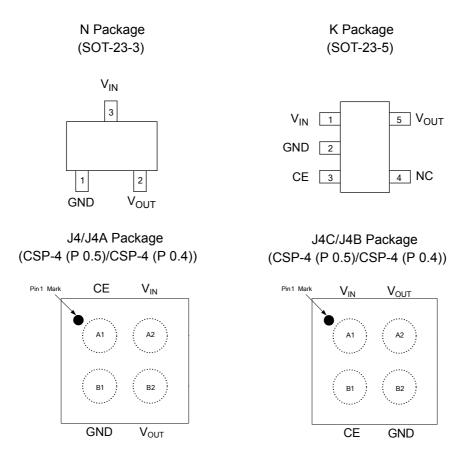


Figure 2. Pin Configuration of AP2121 (Top View)

Pin Description

	Pin Number			Pin Name	Function
SOT-23-3	SOT-23-5	CSP-4 (J4/J4A)	CSP-4 (J4C/J4B)	1 m Name	runction
3	1	A2	A1	V _{IN}	Input voltage
1	2	В1	В2	GND	Ground
	3	A1	B1	CE	Active high enable input pin. Logic high=enable, logic low=shutdown
	4			NC	No connection
2	5	B2	A2	V _{OUT}	Regulated output voltage

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Functional Block Diagram

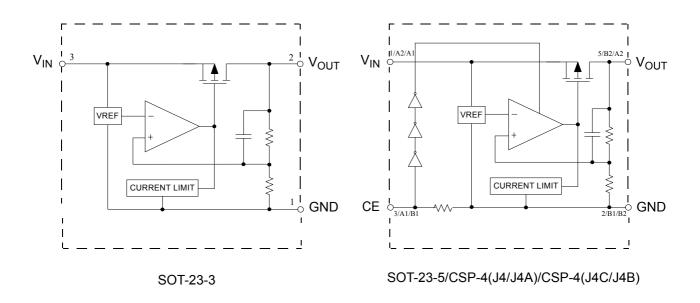
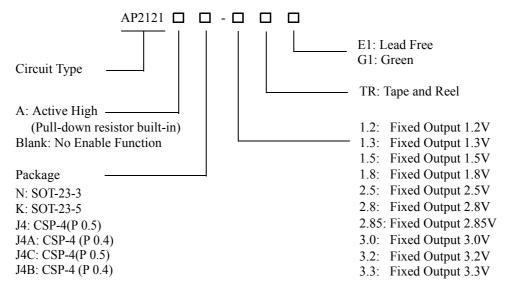


Figure 3. Functional Block Diagram of AP2121

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Ordering Information



Package	Temperature	Condition	Part No	umber	Marki	ng ID	Packing
1 ackage	Range	Condition	Lead Free	Green	Lead Free	Green	Type
			AP2121N-1.2TRE1	AP2121N-1.2TRG1	EF9	GF9	Tape & Reel
			AP2121N-1.3TRE1	AP2121N-1.3TRG1	EG9	GG9	Tape & Reel
			AP2121N-1.5TRE1	AP2121N-1.5TRG1	EF1	GF1	Tape & Reel
			AP2121N-1.8TRE1	AP2121N-1.8TRG1	EF3	GF3	Tape & Reel
SOT-23-3	-40 to 85°C		AP2121N-2.5TRE1	AP2121N-2.5TRG1	EF4	GF4	Tape & Reel
			AP2121N-2.8TRE1	AP2121N-2.8TRG1	EF5	GF5	Tape & Reel
			AP2121N-3.0TRE1	AP2121N-3.0TRG1	EF6	GF6	Tape & Reel
			AP2121N-3.2TRE1	AP2121N-3.2TRG1	EF7	GF7	Tape & Reel
			AP2121N-3.3TRE1	AP2121N-3.3TRG1	EF8	GF8	Tape & Reel
		Active High (Pull-down resistor built-in)	AP2121AK-1.2TRE1	AP2121AK-1.2TRG1	E1T	G1T	Tape & Reel
		Active High (Pull-down resistor built-in)	AP2121AK-1.3TRE1	AP2121AK-1.3TRG1	E1R	G1R	Tape & Reel
		Active High (Pull-down resistor built-in)	AP2121AK-1.5TRE1	AP2121AK-1.5TRG1	E1Z	G1Z	Tape & Reel
		Active High (Pull-down resistor built-in)	AP2121AK-1.8TRE1	AP2121AK-1.8TRG1	E1U	G1U	Tape & Reel
SOT-23-5	-40 to 85°C	Active High (Pull-down resistor built-in)	AP2121AK-2.5TRE1	AP2121AK-2.5TRG1	E1V	G1V	Tape & Reel
		Active High (Pull-down resistor built-in)	AP2121AK-2.8TRE1	AP2121AK-2.8TRG1	E1W	G1W	Tape & Reel
		Active High (Pull-down resistor built-in)	AP2121AK-3.0TRE1	AP2121AK-3.0TRG1	E1X	G1X	Tape & Reel
		Active High (Pull-down resistor built-in)	AP2121AK-3.2TRE1	AP2121AK-3.2TRG1	E3Z	G3Z	Tape & Reel
		Active High (Pull-down resistor built-in)	AP2121AK-3.3TRE1	AP2121AK-3.3TRG1	E1Y	G1Y	Tape & Reel



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Ordering Information (Continued)

Daalaasa	Temperature	Condition	Part	Number	Marki	ng ID	Packing
Package	Range	Condition	Lead Free	Green	Lead Free	Green	Type
		0.4 Pitch		AP2121AJ4A- 1.2TRG1		СВ	Tape & Reel
		0.4 Pitch		AP2121AJ4A- 1.3TRG1		CC	Tape & Reel
		0.4 Pitch		AP2121AJ4A- 1.5TRG1		CD	Tape & Reel
		0.4 Pitch		AP2121AJ4A- 1.8TRG1		CE	Tape & Reel
CSP-4	40 . 0.500	0.4 Pitch		AP2121AJ4A- 2.5TRG1		CF	Tape & Reel
CSF-4	-40 to 85°C	0.4 Pitch		AP2121AJ4A- 2.8TRG1		CG	Tape & Reel
		0.4 Pitch		AP2121AJ4A- 2.85TRG1		DD	Tape & Reel
		0.4 Pitch		AP2121AJ4A- 3.0TRG1		СН	Tape & Reel
		0.4 Pitch		AP2121AJ4A- 3.2TRG1		DA	Tape & Reel
		0.4 Pitch		AP2121AJ4A- 3.3TRG1		DB	Tape & Reel
		0.5 Pitch		AP2121AJ4- 1.2TRG1		BA	Tape & Reel
		0.5 Pitch		AP2121AJ4- 1.3TRG1		ВВ	Tape & Reel
		0.5 Pitch		AP2121AJ4- 1.5TRG1		ВС	Tape & Reel
		0.5 Pitch		AP2121AJ4- 1.8TRG1		BD	Tape & Reel
CSP-4	-40 to 85°C	0.5 Pitch		AP2121AJ4- 2.5TRG1		BE	Tape & Reel
CSF-4	-40 to 85°C	0.5 Pitch		AP2121AJ4- 2.8TRG1		BF	Tape & Reel
		0.5 Pitch		AP2121AJ4- 2.85TRG1		DC	Tape & Reel
		0.5 Pitch		AP2121AJ4- 3.0TRG1		BG	Tape & Reel
		0.5 Pitch		AP2121AJ4- 3.2TRG1		ВН	Tape & Reel
		0.5 Pitch		AP2121AJ4- 3.3TRG1		CA	Tape & Reel



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Ordering Information (Continued)

Package	Temperature	Condition	Part	Number	Marki	ng ID	Packing
гаскаде	Range	Condition	Lead Free	Green	Lead Free	Green	Type
		0.4 Pitch		AP2121AJ4B- 1.2TRG1		DE	Tape & Reel
		0.4 Pitch		AP2121AJ4B- 1.3TRG1		DF	Tape & Reel
		0.4 Pitch		AP2121AJ4B- 1.5TRG1		DG	Tape & Reel
		0.4 Pitch		AP2121AJ4B- 1.8TRG1		DH	Tape & Reel
CSP-4	-40 to 85°C	0.4 Pitch		AP2121AJ4B- 2.5TRG1		EA	Tape & Reel
C31 -4	-40 to 85°C	0.4 Pitch		AP2121AJ4B- 2.8TRG1		EB	Tape & Reel
		0.4 Pitch		AP2121AJ4B- 2.85TRG1		EC	Tape & Reel
		0.4 Pitch		AP2121AJ4B- 3.0TRG1		ED	Tape & Reel
		0.4 Pitch		AP2121AJ4B- 3.2TRG1		EE	Tape & Reel
		0.4 Pitch		AP2121AJ4B- 3.3TRG1		EF	Tape & Reel
		0.5 Pitch		AP2121AJ4C- 1.2TRG1		EG	Tape & Reel
		0.5 Pitch		AP2121AJ4C- 1.3TRG1		ЕН	Tape & Reel
		0.5 Pitch		AP2121AJ4C- 1.5TRG1		FA	Tape & Reel
		0.5 Pitch		AP2121AJ4C- 1.8TRG1		FB	Tape & Reel
CSP-4	-40 to 85°C	0.5 Pitch		AP2121AJ4C- 2.5TRG1		FC	Tape & Reel
C51 -4	-40 to 83 C	0.5 Pitch		AP2121AJ4C- 2.8TRG1		FD	Tape & Reel
		0.5 Pitch		AP2121AJ4C- 2.85TRG1		FE	Tape & Reel
		0.5 Pitch		AP2121AJ4C- 3.0TRG1		FF	Tape & Reel
		0.5 Pitch		AP2121AJ4C- 3.2TRG1		FG	Tape & Reel
		0.5 Pitch		AP2121AJ4C- 3.3TRG1		FH	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green packages.



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Absolute Maximum Ratings (Note 1)

Parameter	Symbol	Value		Unit
Input Voltage	V _{IN}	6.5		V
Enable Input Voltage	V _{CE}	-0.3 to V	V _{IN} +0.3	V
Output Current	I _{OUT}	300		mA
Junction Temperature	T_{J}	150		°C
Storage Temperature Range	T _{STG}	-65 to 150		°C
Lead Temperature (Soldering, 10sec)	T_{LEAD}	260		°C
		SOT-23-3	250	
Thermal Resistance (Junction to Ambient) (Note 2)	$\theta_{ m JA}$	SOT-23-5	250	°C/W
		CSP-4	126	
ESD (Human Body Model)	ESD	2000		V
ESD (Machine Model)	ESD	20	0	V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Note 2: Absolute maximum ratings indicate limits beyond which damage to the component may occur. Electrical specifications do not apply when operating the device outside of its operating ratings. The maximum allowable power dissipation is a function of the maximum junction temperature, $T_{J(max)}$, the junction-to-ambient thermal resistance, θ_{JA} , and the ambient temperature, T_A . The maximum allowable power dissipation at any ambient temperature is calculated using: $P_{D(max)} = (T_{J(max)} - T_A)/\theta_{JA}$. Exceeding the maximum allowable power dissipation will result in excessive die temperature.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Input Voltage	$V_{\rm IN}$	2	6	V
Operating Ambient Temperature Range	$T_{\mathbf{A}}$	-40	85	°C

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Electrical Characteristics AP2121-1.2 Electrical Characteristics

 $(V_{IN}\!\!=\!\!2.2V,\,T_{J}\!\!=\!\!25^{o}\!C,\,C_{IN}\!\!=\!\!1\mu\text{F},\,C_{OUT}\!\!=\!\!1\mu\text{F},\,\textbf{Bold}\,\text{typeface applies over -40}^{o}\!C\!\!\leq\!\!T_{J}\!\!\leq\!\!85^{o}\!C,\,\text{unless otherwise specified.})$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage	V _{OUT}	V _{IN} =2.2V 1mA≤I _{OUT} ≤30mA	1.176	1.2	1.224	V
Input Voltage	V _{IN}				6	V
Output Current	I _{OUT}	V _{IN} -V _{OUT} =1V	200			mA
Load Regulation	V _{RLOAD}	V _{IN} =2.2V 1mA≤I _{OUT} ≤80mA		12	40	mV
Line Regulation	V _{RLINE}	$ \begin{array}{c} 2.2 \text{V} \leq \text{V}_{\text{IN}} \leq 6 \text{V} \\ \text{I}_{\text{OUT}} = 30 \text{mA} \end{array} $		4	16	mV
		I _{OUT} =10mA		700	900	
Dropout Voltage	$ m V_{DROP}$	I _{OUT} =100mA		700	900	mV
	V DROP	I _{OUT} =150mA		700	900	111 V
		I _{OUT} =200mA		700	900	
Quiescent Current	I_Q	V _{IN} =2.2V, I _{OUT} =0mA		25	50	μA
Standby Current	I _{STD}	V _{IN} =2.2V V _{CE} in OFF mode		0.1	1	μА
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p, f=1kHz V _{IN} =2.2V		70		dB
Output Voltage	$\Delta V_{ m OUT}/\Delta T$	I _{OUT} =30mA		±120		μV/°C
Temperature Coefficient	$(\Delta V_{OUT}/V_{OUT})/\Delta T$	1 _{OUT} -30IIIA		±100		ppm/°C
Short Current Limit	I _{LIMIT}	V _{OUT} =0V		50		mA
RMS Output Noise	$V_{ m NOISE}$	T _A =25°C 10Hz ≤f≤100kHz		30		μVrms
CE "High" Voltage		CE input voltage "High"	1.5			V
CE "Low" Voltage		CE input voltage "Low"			0.25	V
CE Pull-down Resistance	R _{PD}		2.5	5	10	ΜΩ
		SOT-23-3		74		
Thermal Resistance (Junction to Case)	$ heta_{ m JC}$	SOT-23-5		74		°C/W
(Canonin to Case)		CSP-4		5		1

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Electrical Characteristics (Continued) AP2121-1.3 Electrical Characteristics

 $(V_{IN}=2.3V, T_J=25^{o}C, C_{IN}=1\mu F, C_{OUT}=1\mu F, \textbf{Bold}$ typeface applies over $-40^{o}C \le T_J \le 85^{o}C$, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage	$V_{ m OUT}$	V _{IN} =2.3V 1mA≤I _{OUT} ≤30mA	1.274	1.3	1.326	V
Input Voltage	V _{IN}				6	V
Output Current	I _{OUT}	V _{IN} -V _{OUT} =1V	200			mA
Load Regulation	V _{RLOAD}	V _{IN} =2.3V 1mA≤I _{OUT} ≤80mA		12	40	mV
Line Regulation	V_{RLINE}	$ \begin{array}{c} 2.3\text{V} \leq \text{V}_{\text{IN}} \leq 6\text{V} \\ \text{I}_{\text{OUT}} = 30\text{mA} \end{array} $		4	16	mV
		I _{OUT} =10mA		600	800	
Dropout Voltage	$ m V_{DROP}$	I _{OUT} =100mA		600	800	mV
	, DKOb	I _{OUT} =150mA		600	800	1111
		I _{OUT} =200mA		600	800	
Quiescent Current	I_Q	V _{IN} =2.3V, I _{OUT} =0mA		25	50	μА
Standby Current	I_{STD}	V _{IN} =2.3V V _{CE} in OFF mode		0.1	1	μА
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p, f=1kHz V _{IN} =2.3V		70		dB
Output Voltage	$\Delta V_{ m OUT}/\Delta T$	I -20m A		±130		μV/°C
Temperature Coefficient	$(\Delta V_{OUT}/V_{OUT})/\Delta T$	I _{OUT} =30mA		±100		ppm/°C
Short Current Limit	I _{LIMIT}	V _{OUT} =0V		50		mA
RMS Output Noise	V _{NOISE}	T _A =25°C 10Hz ≤f≤100kHz		30		μVrms
CE "High" Voltage		CE input voltage "High"	1.5			V
CE "Low" Voltage		CE input voltage "Low"			0.25	V
CE Pull-down Resistance	R _{PD}		2.5	5	10	ΜΩ
		SOT-23-3		74		
Thermal Resistance (Junction to Case)	$ heta_{ m JC}$	SOT-23-5		74		°C/W
(sunction to case)		CSP-4		5		-



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Electrical Characteristics (Continued) AP2121-1.5 Electrical Characteristics

 $(V_{IN}=2.5V, T_J=25^{o}C, C_{IN}=1\mu F, C_{OUT}=1\mu F, \textbf{Bold}$ typeface applies over $-40^{o}C \le T_J \le 85^{o}C$, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit	
Output Voltage	$ m V_{OUT}$	V _{IN} =2.5V 1mA≤I _{OUT} ≤30mA	1.47	1.5	1.53	V	
Input Voltage	V _{IN}				6	V	
Output Current	I_{OUT}	V _{IN} -V _{OUT} =1V	200			mA	
Load Regulation	V_{RLOAD}	V _{IN} =2.5V 1mA≤I _{OUT} ≤80mA		12	40	mV	
Line Regulation	V_{RLINE}	$2.3V \le V_{IN} \le 6V$ $I_{OUT} = 30mA$		4	16	mV	
		I _{OUT} =10mA		400	600		
Dropout Voltage	Vanor	I _{OUT} =100mA		400	600	mV	
Diopout voltage	V_{DROP}	I _{OUT} =150mA		400	600	- III V	
		I _{OUT} =200mA		400	600		
Quiescent Current	I_Q	V _{IN} =2.5V, I _{OUT} =0mA		25	50	μА	
Standby Current	I_{STD}	V _{IN} =2.5V V _{CE} in OFF mode		0.1	1	μА	
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p, f=1kHz V _{IN} =2.5V		70		dB	
Output Voltage	$\Delta V_{ m OUT}/\Delta T$	I -20m A		±150		μV/°C	
Temperature Coefficient	$(\Delta V_{OUT}/V_{OUT})/\Delta T$	I _{OUT} =30mA		±100		ppm/°C	
Short Current Limit	I _{LIMIT}	V _{OUT} =0V		50		mA	
RMS Output Noise	V _{NOISE}	T _A =25°C 10Hz ≤f≤100kHz		30		μVrms	
CE "High" Voltage		CE input voltage "High"	1.5			V	
CE "Low" Voltage		CE input voltage "Low"			0.25	V	
CE Pull-down Resistance	R _{PD}		2.5	5	10	ΜΩ	
		SOT-23-3		74		°C/W	
Thermal Resistance (Junction to Case)	$ heta_{ m JC}$	SOT-23-5		74			
(valietion to case)		CSP-4		5		1	

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Electrical Characteristics (Continued) AP2121-1.8 Electrical Characteristics

 $(V_{IN}=2.8V, T_J=25^{o}C, C_{IN}=1\mu F, C_{OUT}=1\mu F, \textbf{Bold}$ typeface applies over $-40^{o}C \le T_J \le 85^{o}C$, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage	$V_{ m OUT}$	V _{IN} =2.8V 1mA≤I _{OUT} ≤30mA	1.764	1.8	1.836	V
Input Voltage	V_{IN}				6	V
Output Current	I_{OUT}	V _{IN} -V _{OUT} =1V	200			mA
Load Regulation	V _{RLOAD}	V _{IN} =2.8V 1mA≤I _{OUT} ≤80mA		12	40	mV
Line Regulation	V_{RLINE}	2.3V≤V _{IN} ≤6V I _{OUT} =30mA		4	16	mV
		I _{OUT} =10mA		20	40	
Dropout Voltage	Vanor	I _{OUT} =100mA		150	300	mV
	$ m V_{DROP}$	I _{OUT} =150mA		200	400	111 V
		I _{OUT} =200mA		250	500	
Quiescent Current	I_Q	V _{IN} =2.8V, I _{OUT} =0mA		25	50	μA
Standby Current	I_{STD}	V _{IN} =2.8V V _{CE} in OFF mode		0.1	1	μА
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p, f=1kHz V _{IN} =2.8V		70		dB
Output Voltage	$\Delta V_{ m OUT}/\Delta T$	I -20m A		±180		μV/°C
Temperature Coefficient	$(\Delta V_{OUT}/V_{OUT})/\Delta T$	I _{OUT} =30mA		±100		ppm/°C
Short Current Limit	I _{LIMIT}	V _{OUT} =0V		50		mA
RMS Output Noise	V _{NOISE}	T _A =25°C 10Hz ≤f≤100kHz		30		μVrms
CE "High" Voltage		CE input voltage "High"	1.5			V
CE "Low" Voltage		CE input voltage "Low"			0.25	V
CE Pull-down Resistance	R _{PD}		2.5	5	10	ΜΩ
		SOT-23-3		74		
Thermal Resistance (Junction to Case)	$\theta_{ m JC}$	SOT-23-5		74		°C/W
(sunction to case)		CSP-4		5		-

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Electrical Characteristics (Continued) AP2121-2.5 Electrical Characteristics

 $(V_{IN}\!=\!3.5V,\,T_{J}\!=\!25^{o}C,\,C_{IN}\!=\!1\mu\text{F},\,C_{OUT}\!=\!1\mu\text{F},\,\textbf{Bold}\,\,\text{typeface applies over -40}{}^{o}C\!\leq\!T_{J}\!\leq\!85^{o}C,\,\text{unless otherwise specified.})$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage	V _{OUT}	V _{IN} =3.5V 1mA≤I _{OUT} ≤30mA	2.45	2.5	2.55	V
Input Voltage	V _{IN}				6	V
Output Current	I _{OUT}	V _{IN} -V _{OUT} =1V	200			mA
Load Regulation	V _{RLOAD}	V_{IN} =3.5V 1mA \leq I _{OUT} \leq 80mA		12	40	mV
Line Regulation	V _{RLINE}	3V≤V _{IN} ≤6V I _{OUT} =30mA		4	16	mV
		I _{OUT} =10mA		20	40	
Dropout Voltage	${ m V}_{ m DROP}$	I _{OUT} =100mA		150	300	mV
	T DROP	I _{OUT} =150mA		200	400	111 V
		I _{OUT} =200mA		250	500	
Quiescent Current	I_Q	V_{IN} =3.5V, I_{OUT} =0mA		25	50	μΑ
Standby Current	I_{STD}	V _{IN} =3.5V V _{CE} in OFF mode		0.1	1	μА
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p, f=1kHz V _{IN} =3.5V		70		dB
Output Voltage	$\Delta V_{ m OUT}/\Delta T$	I _{OUT} =30mA		±250		μV/°C
Temperature Coefficient	$(\Delta V_{OUT}/V_{OUT})/\Delta T$	10UT-30IIIA		±100		ppm/°C
Short Current Limit	I _{LIMIT}	V _{OUT} =0V		50		mA
RMS Output Noise	V _{NOISE}	T _A =25°C 10Hz ≤f≤100kHz		30		μVrms
CE "High" Voltage		CE input voltage "High"	1.5			V
CE "Low" Voltage		CE input voltage "Low"			0.25	V
CE Pull-down Resistance	R _{PD}		2.5	5	10	ΜΩ
		SOT-23-3		74		
Thermal Resistance (Junction to Case)	$\theta_{ m JC}$	SOT-23-5		74		°C/W
(canonical case)		CSP-4		5		•

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Electrical Characteristics (Continued) AP2121-2.8 Electrical Characteristics

 $(V_{IN}=3.8V, T_J=25^{o}C, C_{IN}=1\mu F, C_{OUT}=1\mu F, \textbf{Bold}$ typeface applies over $-40^{o}C \le T_J \le 85^{o}C$, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage	V _{OUT}	V_{IN} =3.8V 1mA \leq I _{OUT} \leq 30mA	2.744	2.8	2.856	V
Input Voltage	V _{IN}				6	V
Output Current	I _{OUT}	V _{IN} -V _{OUT} =1V	200			mA
Load Regulation	V _{RLOAD}	V _{IN} =3.8V 1mA≤I _{OUT} ≤80mA		12	40	mV
Line Regulation	V_{RLINE}	$ \begin{array}{c} 3.3\text{V} \leq \text{V}_{\text{IN}} \leq 6\text{V} \\ \text{I}_{\text{OUT}} = 30\text{mA} \end{array} $		4	16	mV
		I _{OUT} =10mA		20	40	
Dropout Voltage	$ m V_{DROP}$	I _{OUT} =100mA		150	300	mV
	DROP	I _{OUT} =150mA		200	400	111 4
		I _{OUT} =200mA		250	500	
Quiescent Current	I_Q	V _{IN} =3.8V, I _{OUT} =0mA		25	50	μА
Standby Current	I_{STD}	V _{IN} =3.8V V _{CE} in OFF mode		0.1	1	μА
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p, f=1kHz V _{IN} =3.8V		70		dB
Output Voltage	$\Delta V_{ m OUT}/\Delta T$	I -20m A		±280		μV/°C
Temperature Coefficient	$(\Delta V_{OUT}/V_{OUT})/\Delta T$	I _{OUT} =30mA		±100		ppm/oC
Short Current Limit	I _{LIMIT}	V _{OUT} =0V		50		mA
RMS Output Noise	V _{NOISE}	T _A =25°C 10Hz ≤f≤100kHz		30		μVrms
CE "High" Voltage		CE input voltage "High"	1.5			V
CE "Low" Voltage		CE input voltage "Low"			0.25	V
CE Pull-down Resistance	R_{PD}		2.5	5	10	ΜΩ
		SOT-23-3		74		
Thermal Resistance (Junction to Case)	$ heta_{ m JC}$	SOT-23-5		74		°C/W
(valietion to case)		CSP-4		5		1



AP2121

Electrical Characteristics (Continued) AP2121-2.85 Electrical Characteristics

 $(V_{IN}=3.85V, T_J=25^{\circ}C, C_{IN}=1\mu F, C_{OUT}=1\mu F, \textbf{Bold}$ typeface applies over $-40^{\circ}C \le T_J \le 85^{\circ}C$, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage	V _{OUT}	V _{IN} =3.85V 1mA≤I _{OUT} ≤30mA	2.793	2.85	2.907	V
Input Voltage	V _{IN}				6	V
Output Current	I _{OUT}	V _{IN} -V _{OUT} =1V	200			mA
Load Regulation	V _{RLOAD}	V _{IN} =3.85V 1mA≤I _{OUT} ≤80mA		12	40	mV
Line Regulation	V _{RLINE}	$\begin{array}{c} 3.3\text{V} \leq \text{V}_{\text{IN}} \leq 6\text{V} \\ \text{I}_{\text{OUT}} = 30\text{mA} \end{array}$		4	16	mV
		I _{OUT} =10mA		20	40	mV
Dropout Voltage	$ m V_{DROP}$	I _{OUT} =100mA		150	300	
Dropout voltage	DROP	I _{OUT} =150mA		200	400	
		I _{OUT} =200mA		250	500	
Quiescent Current	I_Q	V _{IN} =3.85V, I _{OUT} =0mA		25	50	μA
Standby Current	I _{STD}	V _{IN} =3.85V V _{CE} in OFF mode		0.1	1	μА
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p, f=1kHz V _{IN} =3.85V		70		dB
Output Voltage Temperature Coefficient	$ \begin{array}{ c c c c c }\hline \Delta V_{OUT}/\Delta T & & & & & \\\hline & (\Delta V_{OUT}/V_{OUT})/\Delta T & & & & & \\\hline \end{array} $	L _{0.1.m} =30m Δ		±280		μV/°C
			±100		ppm/oC	
Short Current Limit	I _{LIMIT}	V _{OUT} =0V		50		mA
RMS Output Noise	V _{NOISE}	T _A =25°C 10Hz ≤f≤100kHz		30		μVrms
CE "High" Voltage		CE input voltage "High"	1.5			V
CE "Low" Voltage		CE input voltage "Low"			0.25	V
CE Pull-down Resistance	R_{PD}		2.5	5	10	ΜΩ
Thermal Resistance (Junction to Case)	$\theta_{ m JC}$	CSP-4		5		°C/W



AP2121

Electrical Characteristics (Continued) AP2121-3.0 Electrical Characteristics

 $(V_{IN}\!\!=\!\!4V,T_{J}\!\!=\!\!25^{o}\!C,C_{IN}\!\!=\!\!1\mu\text{F},C_{OUT}\!\!=\!\!1\mu\text{F},\textbf{Bold} \text{ typeface applies over -}40^{o}\!C\!\!\leq\!\!T_{J}\!\!\leq\!\!85^{o}\!C,\text{ unless otherwise specified.})$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage	V _{OUT}	V _{IN} =4V 1mA≤I _{OUT} ≤30mA	2.94	3.0	3.06	V
Input Voltage	V _{IN}				6	V
Output Current	I _{OUT}	V _{IN} -V _{OUT} =1V	200			mA
Load Regulation	V _{RLOAD}	V _{IN} =4V 1mA≤I _{OUT} ≤80mA		12	40	mV
Line Regulation	V _{RLINE}	$3.5V \le V_{IN} \le 6V$ $I_{OUT} = 30 \text{mA}$		4	16	mV
		I _{OUT} =10mA		20	40	
Dropout Voltage	V_{DROP}	I _{OUT} =100mA		150	300	mV
Dropout voltage	* DROP	I _{OUT} =150mA		200	400	111 V
		I _{OUT} =200mA		250	500	
Quiescent Current	I_Q	V _{IN} =4V, I _{OUT} =0mA		25	50	μΑ
Standby Current	I _{STD}	V _{IN} =4V V _{CE} in OFF mode		0.1	1	μΑ
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p, f=1kHz V _{IN} =4V		70		dB
Output Voltage	$\Delta V_{ m OUT}/\Delta T$	I _{OUT} =30mA		±300		μV/°C
Temperature Coefficient	$(\Delta V_{OUT}/V_{OUT})/\Delta T$			±100		ppm/°C
Short Current Limit	I _{LIMIT}	V _{OUT} =0V		50		mA
RMS Output Noise	V _{NOISE}	T _A =25°C 10Hz ≤f≤100kHz		30		μVrms
CE "High" Voltage		CE input voltage "High"	1.5			V
CE "Low" Voltage		CE input voltage "Low"			0.25	V
CE Pull-down Resistance	R _{PD}		2.5	5	10	ΜΩ
Thermal Resistance (Junction to Case)	Hig	SOT-23-3		74		
		SOT-23-5		74		°C/W
		CSP-4		5		1



AP2121

Electrical Characteristics (Continued) AP2121-3.2 Electrical Characteristics

 $(V_{IN}=4.2V, T_J=25^{o}C, C_{IN}=1\mu F, C_{OUT}=1\mu F, \textbf{Bold}$ typeface applies over $-40^{o}C \le T_J \le 85^{o}C$, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage	V _{OUT}	V _{IN} =4.2V 1mA≤I _{OUT} ≤30mA	3.136	3.2	3.264	V
Input Voltage	V_{IN}				6	V
Output Current	I_{OUT}	V _{IN} -V _{OUT} =1V	200			mA
Load Regulation	V _{RLOAD}	V_{IN} =4.2V 1mA \leq I _{OUT} \leq 80mA		12	40	mV
Line Regulation	V _{RLINE}	$3.7V \le V_{IN} \le 6V$ $I_{OUT} = 30 \text{mA}$		4	16	mV
		I _{OUT} =10mA		20	40	
Dropout Voltage	$ m V_{DROP}$	I _{OUT} =100mA		150	300	mV
Diopout voltage	, DROb	I _{OUT} =150mA		200	400	1111
		I _{OUT} =200mA		250	500	
Quiescent Current	I_Q	V _{IN} =4.2V, I _{OUT} =0mA		25	50	μА
Standby Current	I_{STD}	V _{IN} =4.2V V _{CE} in OFF mode		0.1	1	μА
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p, f=1kHz V _{IN} =4.2V		70		dB
Output Voltage	$\Delta V_{ m OUT}/\Delta T$	I _{OUT} =30mA		±320		μV/°C
Temperature Coefficient	$(\Delta V_{OUT}/V_{OUT})/\Delta T$			±100		ppm/oC
Short Current Limit	I _{LIMIT}	V _{OUT} =0V		50		mA
RMS Output Noise	V _{NOISE}	T _A =25°C 10Hz ≤f≤100kHz		30		μVrms
CE "High" Voltage		CE input voltage "High"	1.5			V
CE "Low" Voltage		CE input voltage "Low"			0.25	V
CE Pull-down Resistance	R _{PD}		2.5	5	10	ΜΩ
Thermal Resistance (Junction to Case)	Hic	SOT-23-3		74		
		SOT-23-5		74		°C/W
		CSP-4		5		1



AP2121

Electrical Characteristics (Continued) AP2121-3.3 Electrical Characteristics

 $(V_{IN}=4.3V, T_J=25^{o}C, C_{IN}=1\mu F, C_{OUT}=1\mu F, \textbf{Bold}$ typeface applies over $-40^{o}C \le T_J \le 85^{o}C$, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output Voltage	V _{OUT}	V _{IN} =4.3V 1mA≤I _{OUT} ≤30mA	3.234	3.3	3.366	V
Input Voltage	V _{IN}				6	V
Output Current	I _{OUT}	V _{IN} -V _{OUT} =1V	200			mA
Load Regulation	V _{RLOAD}	V_{IN} =4.3V $1mA \le I_{OUT} \le 80mA$		12	40	mV
Line Regulation	V _{RLINE}	3.8V≤V _{IN} ≤6V I _{OUT} =30mA		4	16	mV
		I _{OUT} =10mA		20	40	
Dropout Voltage	V_{DROP}	I _{OUT} =100mA		150	300	mV
Diopout voltage	DROP	I _{OUT} =150mA		200	400	111 V
		I _{OUT} =200mA		250	500	1
Quiescent Current	I_Q	V _{IN} =4.3V, I _{OUT} =0mA		25	50	μA
Standby Current	I _{STD}	V _{IN} =4.3V V _{CE} in OFF mode		0.1	1	μА
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p, f=1kHz V _{IN} =4.3V		70		dB
Output Voltage	$\Delta V_{OUT}/\Delta T$	I _{OUT} =30mA		±330		μV/°C
Temperature Coefficient	$(\Delta V_{OUT}/V_{OUT})/\Delta T$			±100		ppm/°C
Short Current Limit	I _{LIMIT}	V _{OUT} =0V		50		mA
RMS Output Noise	V _{NOISE}	T _A =25°C 10Hz ≤f≤100kHz		30		μVrms
CE "High" Voltage		CE input voltage "High"	1.5			V
CE "Low" Voltage		CE input voltage "Low"			0.25	V
CE Pull-down Resistance	R _{PD}		2.5	5	10	ΜΩ
Thermal Resistance (Junction to Case)	$\theta_{ m JC}$	SOT-23-3		74		
		SOT-23-5		74		°C/W
		CSP-4		5		1



Typical Performance Characteristics

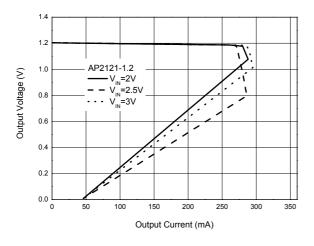


Figure 4. Output Voltage vs. Output Current

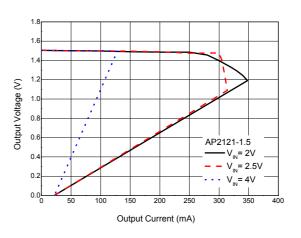


Figure 5. Output Voltage vs. Output Current

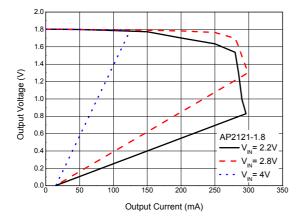


Figure 6. Output Voltage vs. Output Current

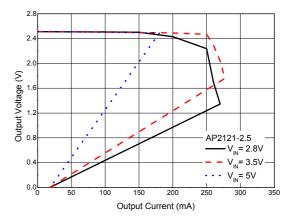
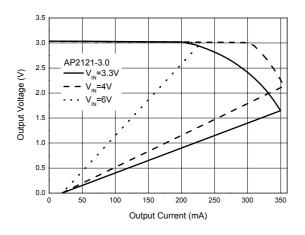


Figure 7. Output Voltage vs. Output Current



Typical Performance Characteristics (Continued)



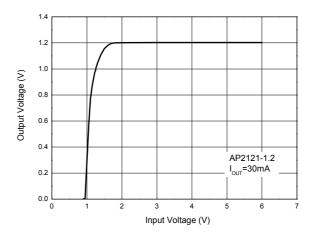
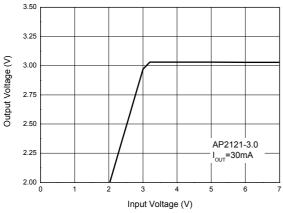
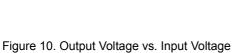


Figure 8. Output Voltage vs. Output Current

Figure 9. Output Voltage vs. Input Voltage





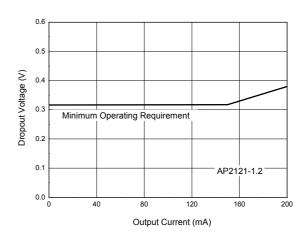
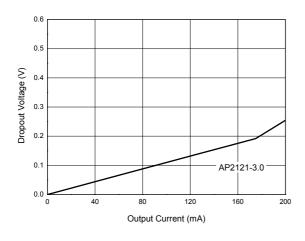


Figure 11. Dropout Voltage vs. Output Current



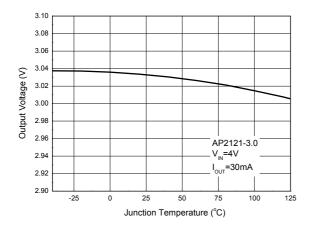
Typical Performance Characteristics (Continued)



1.210 1.206 1.204 Output Voltage (V) 1.202 1.200 1.198 1.196 AP2121-1.2 V_{IN}=2.2V 1.194 I_{out}=30mA 1.192 1.190 75 125 Junction Temperature (°C)

Figure 12. Dropout Voltage vs. Output Current

Figure 13. Output Voltage vs. Junction Temperature



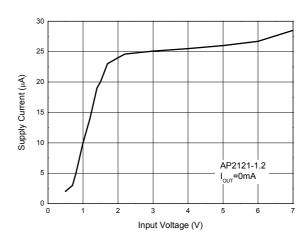
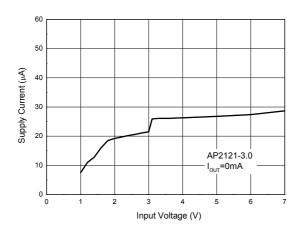


Figure 14. Output Voltage vs. Junction Temperature

Figure 15. Supply Current vs. Input Voltage



Typical Performance Characteristics (Continued)



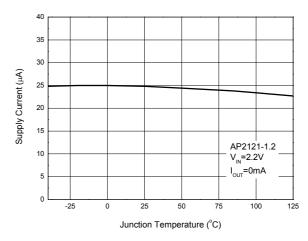
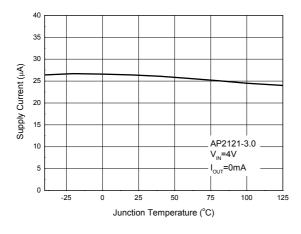


Figure 16. Supply Current vs. Input Voltage

Figure 17. Supply Current vs. Junction Temperature



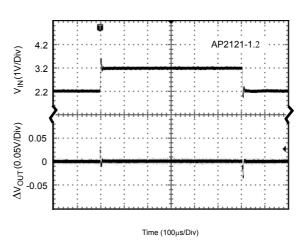


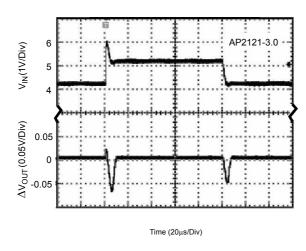
Figure 18. Supply Current vs. Junction Temperature

 $\label{eq:Figure 19. Line Transient}$ (Conditions: I $_{OUT}$ =30mA, C $_{IN}$ =1 $\mu\text{F},$ C $_{OUT}$ =1 $\mu\text{F})$

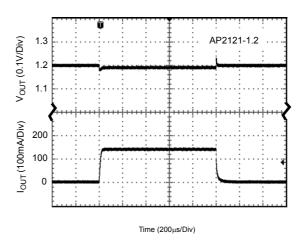
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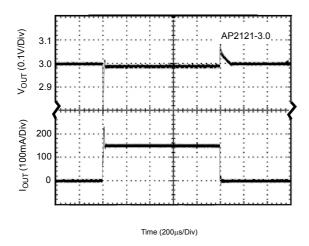
Typical Performance Characteristics (Continued)



 $\label{eq:figure 20. Line Transient}$ (Conditions: I $_{OUT}$ =30mA, C $_{IN}$ =1 $\mu\text{F},$ C $_{OUT}$ =1 $\mu\text{F})$



 $\label{eq:conditions} Figure 21. \ Load \ Transient \\ (Conditions: V_{IN}=2.2V, \ C_{IN}=1\mu F, \ C_{OUT}=1\mu F)$



 $\label{eq:Figure 22. Load Transient}$ (Conditions: V $_{IN}$ =4V, C $_{IN}$ =1 $\mu\text{F},$ C $_{OUT}$ =1 $\mu\text{F})$

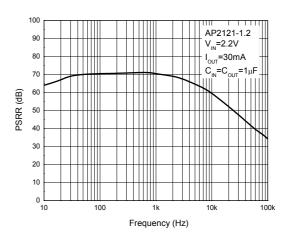


Figure 23. PSRR vs. Frequency

AP2121



HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

Typical Performance Characteristics (Continued)

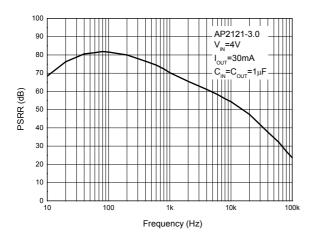
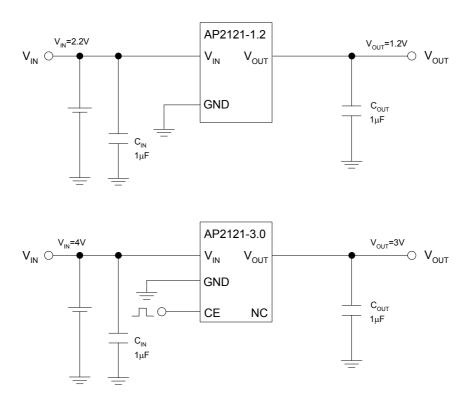


Figure 24. PSRR vs. Frequency



Typical Application



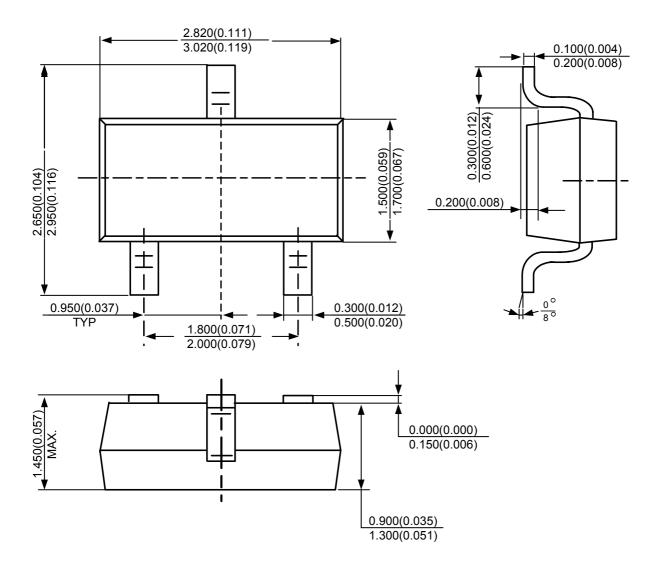
Note: Filter capacitors are required at the AP2121's input and output. $1\mu F$ capacitor is required at the input. The minimum output capacitance required for stability should be more than $1\mu F$ with ESR from 0.01Ω to 100Ω . Ceramic capacitors are recommended.

Figure 25. Typical Application of AP2121



Mechanical Dimensions

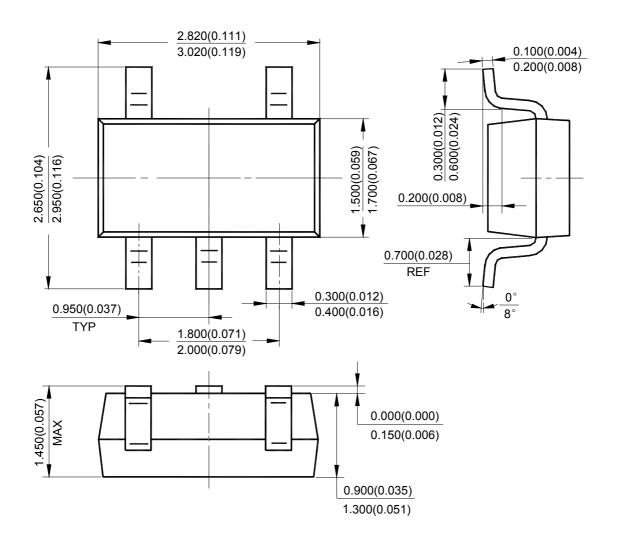
SOT-23-3 Unit: mm(inch)





Mechanical Dimensions (Continued)

SOT-23-5 Unit: mm(inch)



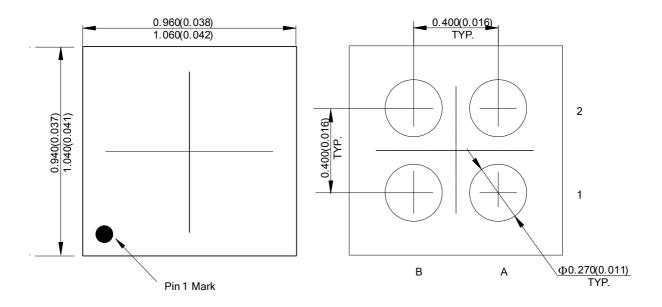
Unit: mm(inch)

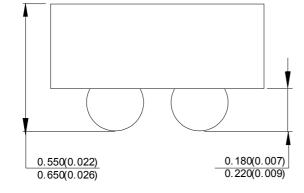


HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

Mechanical Dimensions (Continued)

CSP-4 (P 0.4)





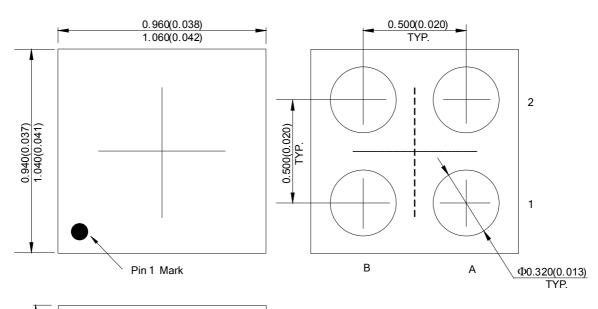
Unit: mm(inch)

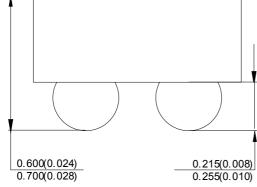


HIGH SPEED, EXTREMELY LOW NOISE LDO REGULATOR

Mechanical Dimensions (Continued)

CSP-4 (P 0.5)









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